NSN 5961-01-327-1486

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-327-1486 **Inclosure Material:** Plastic **Overall Length:** 0.705 inches **Terminal Length:** 0.381 inches **Overall Height:** 0.546 inches **Overall Width:** 0.400 inches **Function For Which Designed:** Rectifier Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 36.0 repetitive peak reverse voltage all semiconductor device diode and 30.0 working peak reverse voltage all semiconductor device diode and 30.0 reverse voltage, instantaneous all semiconductor device diode **Current Rating Per Characteristic:** 30.00 amperes collector current, dc absolute all semiconductor device diode and 300.00 amperes forward current, average preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**